

# PC3H7/PC3Q67Q

## Mini-flat Package, General Purpose Half Pitch Photocoupler

### ■ Features

1. Mini-flat package
2. Half pitch type (lead pitch : 1.27mm)
3. Isolation voltage (Viso : 2 500Vrms)
4. Applicable to infrared ray reflow (230°C, for MAX. 30s)
5. High reliability
6. Taping package **PC3H7** (1ch) **PC3Q67Q** (4ch)
7. Recognized by UL, file No. E64380  
Approved by VDE, No.5922UG

### ■ Applications

1. Programmable controllers

### ■ Package Specifications

| Model No.      | Taping specifications                  |
|----------------|--|
| <b>PC3H7</b>   | Taping reel diameter 330mm (3 000pcs.) |
| <b>PC3Q67Q</b> | Taping reel diameter 330mm (1 000pcs.) |

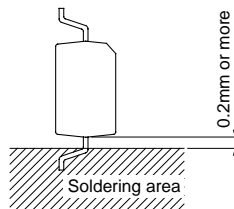
### ■ Absolute Maximum Ratings (Ta=25°C)

|        | Parameter                   | Symbol | Rating      | Unit  |
|--------|-----------------------------|--------|-------------|-------|
| Input  | Forward current             | IF     | 50          | mA    |
|        | *1Peak forward current      | IFM    | 1           | A     |
|        | Reverse voltage             | VR     | 6           | V     |
| Output | Power dissipation           | P      | 70          | mW    |
|        | Collector-emitter voltage   | VCEO   | 70          | V     |
|        | Emitter-collector voltage   | VECO   | 35          | V     |
|        | Collector current           | IC     | 50          | mA    |
|        | Collector power dissipation | Pc     | 150         | mW    |
|        | Total power dissipation     | Ptot   | 170         | mW    |
|        | *2Isolation voltage         | Viso   | 2.5         | kVrms |
|        | Operating temperature       | Topr   | -30 to +100 | °C    |
|        | Storage temperature         | Tstg   | -40 to +125 | °C    |
|        | *3Soldering temperature     | Tsol   | 260         | °C    |

\*1 Pulse width<=100μs, Duty ratio : 0.001

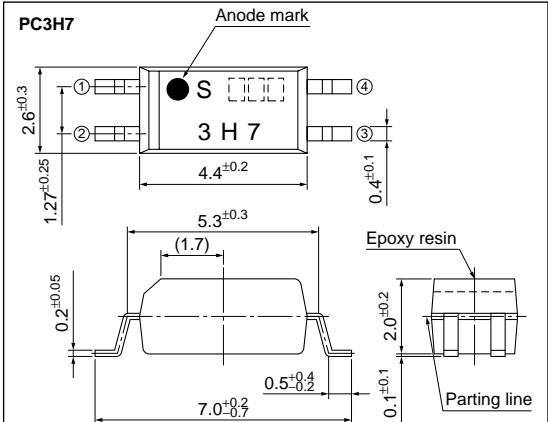
\*2 AC for 1min, 40 to 60%RH, f=60Hz

\*3 For 10s



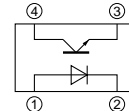
### ■ Outline Dimensions

(Unit : mm)



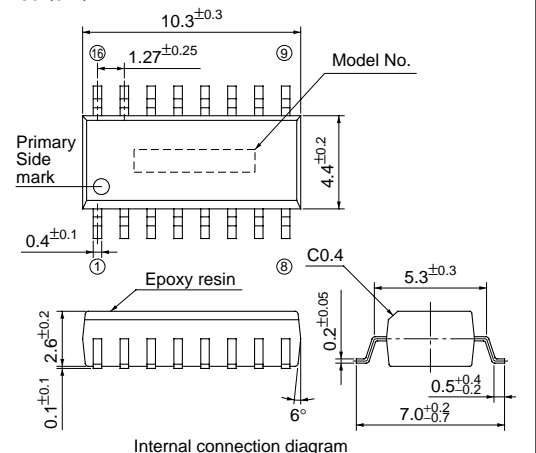
※ ( ) : Reference dimensions

Internal connection diagram

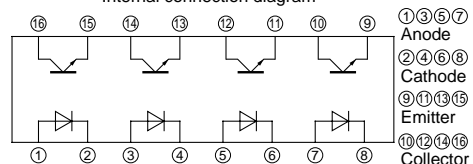


- ① Anode
- ② Cathode
- ③ Emitter
- ④ Collector

### PC3Q67Q



Internal connection diagram



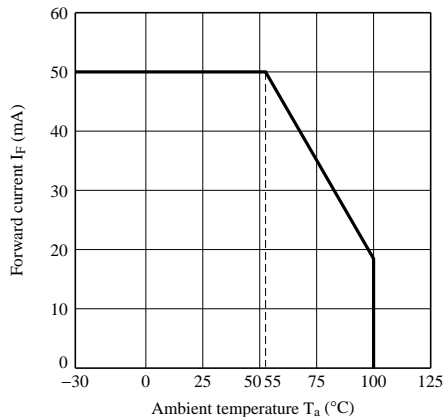
- ①③⑤⑦ Anode
- ②④⑥⑧ Cathode
- ⑨⑪⑬⑮ Emitter
- ⑩⑫⑭⑯ Collector

**Electro-optical Characteristics**

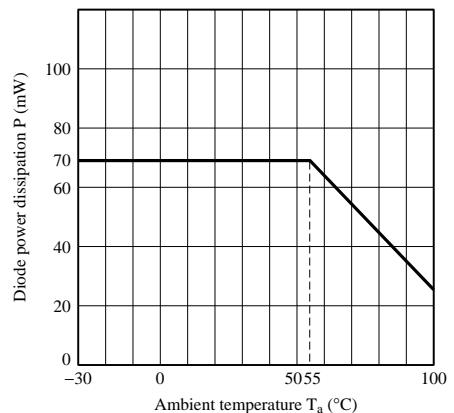
( $T_a=25^\circ\text{C}$ )

| Parameter                |                                      | Symbol         | Conditions           | MIN.                                  | TYP.  | MAX.               | Unit          |               |
|--------------------------|--------------------------------------|----------------|----------------------|---------------------------------------|---|--------------------|---------------|---------------|
| Input                    | Forward voltage                      | $V_F$          | $I_F=20\text{mA}$    | -                                     | 1.2   | 1.4                | V             |               |
|                          | Reverse current                      | $I_R$          | $V_R=4\text{V}$      | -                                     | -   | 10                 | $\mu\text{A}$ |               |
|                          | Terminal capacitance                 | $C_t$          | $V=0, f=1\text{kHz}$ | -                                     | 30  | 250                | pF            |               |
| Output                   | Collector dark current               | <b>PC3H7</b>   | $I_{CEO}$            | $V_{CE}=50\text{V}, I_F=0$            | -   | -                  | 100           | nA            |
|                          |                                      | <b>PC3Q67Q</b> | $I_{CEO}$            | $V_{CE}=20\text{V}, I_F=0$            | -   | -                  | 100           | nA            |
|                          | Collector-emitter breakdown voltage  | <b>PC3H7</b>   | $BV_{CEO}$           | $I_C=0.1\text{mA}, I_F=0$             | 70  | -                  | -             | V             |
|                          |                                      | <b>PC3Q67Q</b> | $BV_{CEO}$           | $I_C=0.1\text{mA}, I_F=0$             | 35  | -                  | -             | V             |
|                          | Emitter-collector breakdown voltage  | $BV_{ECO}$     |                      | $I_E=10\mu\text{A}, I_F=0$            | 6   | -                  | -             | V             |
| Transfer characteristics | Collector current                    | <b>PC3H7</b>   | $I_C$                | $I_F=1\text{mA}, V_{CE}=5\text{V}$    | 0.2   | -                  | 4             | mA            |
|                          |                                      | <b>PC3Q67Q</b> | $I_C$                | $I_F=5\text{mA}, V_{CE}=5\text{V}$    | 2.5   | 5                  | 30            | mA            |
|                          | Collector-emitter saturation voltage | $V_{CE(sat)}$  |                      | $I_F=20\text{mA}$<br>$I_C=1\text{mA}$ | -   | 0.1                | 0.2           | V             |
|                          | Isolation resistance                 | $R_{ISO}$      |                      | DC500V<br>40 to 60%RH                 | $5 \times 10^{10}$  | $1 \times 10^{11}$ | -             | $\Omega$      |
|                          | Floating capacitance                 | $C_f$          |                      | $V=0, f=1\text{MHz}$                  | -   | 0.6                | 1.0           | pF            |
|                          | Response time                        | Rise time      | $t_r$                |                                       | $V_{CE}=2\text{V}$<br>$I_C=2\text{mA}$<br>$R_L=100\Omega$ | -                  | 4             | 18            |
| Fall time                |                                      | $t_f$          |                      |                                       | -   | 3                  | 18            | $\mu\text{s}$ |

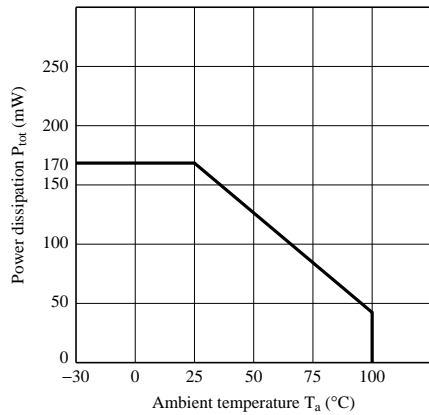
**Fig.1 Forward Current vs. Ambient Temperature**



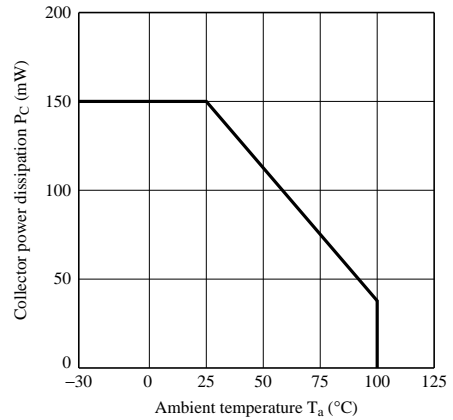
**Fig.2 Diode Power Dissipation vs. Ambient Temperature**



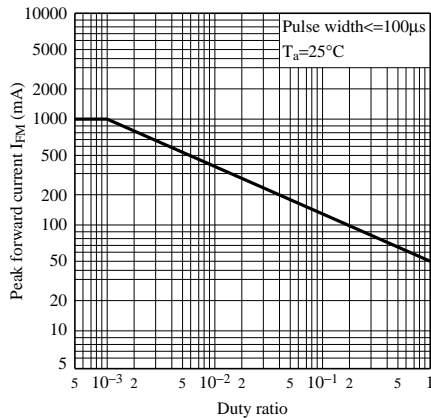
**Fig.3 Collector Power Dissipation vs. Ambient Temperature**



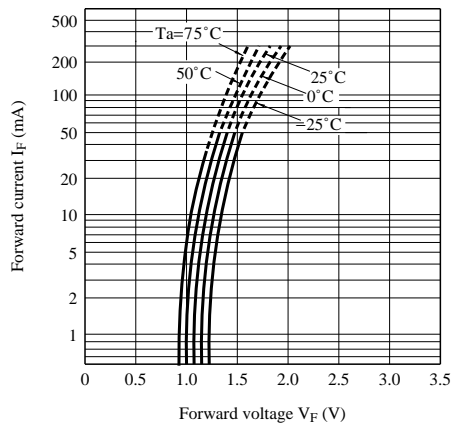
**Fig.4 Total Power Dissipation vs. Ambient Temperature**



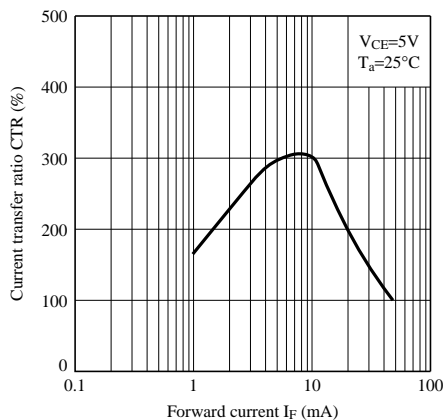
**Fig.5 Peak Forward Current vs. Duty Ratio**



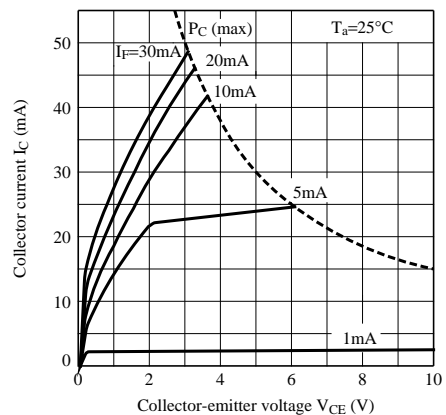
**Fig.6 Forward Current vs. Forward Voltage**



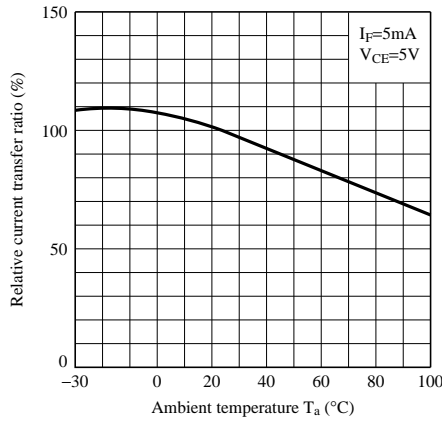
**Fig.7 Current Transfer Ratio vs. Forward Current**



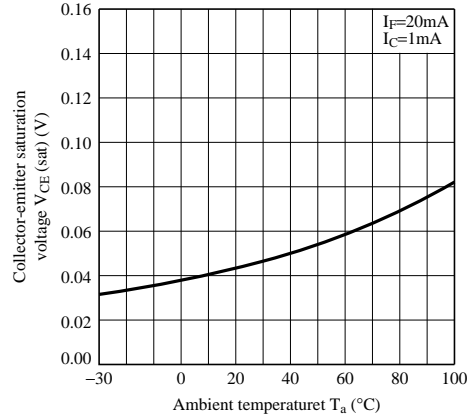
**Fig.8 Collector Current vs. Collector-emitter Voltage**



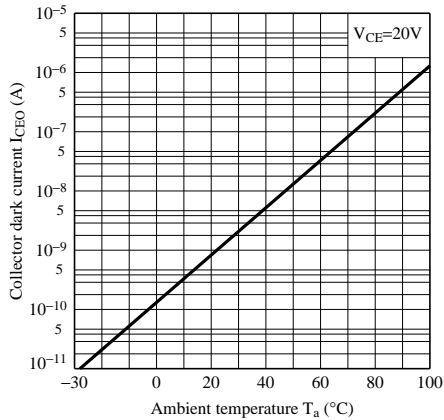
**Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature**



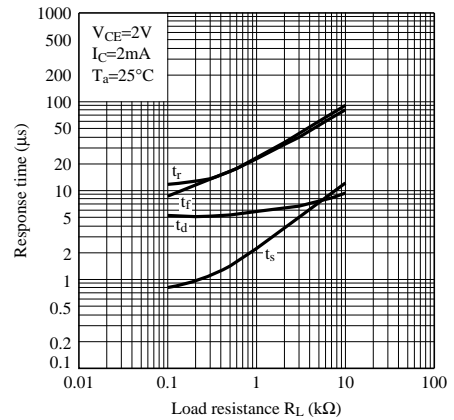
**Fig.10 Collector-emitter Saturation Voltage vs. Ambient Temperature**



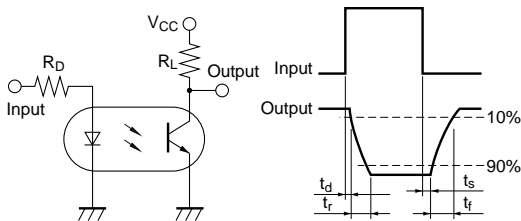
**Fig.11 Collector Dark Current vs. Ambient Temperature**



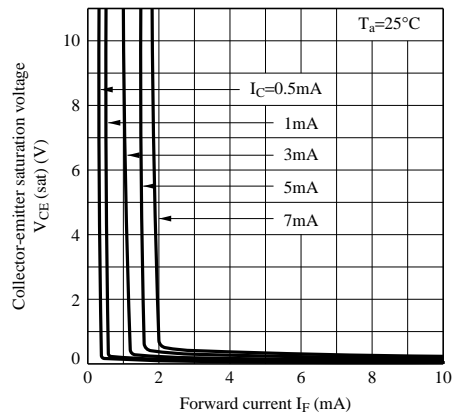
**Fig.12 Response Time vs. Load Resistance**



**Fig.13 Test Circuit for Response Time**

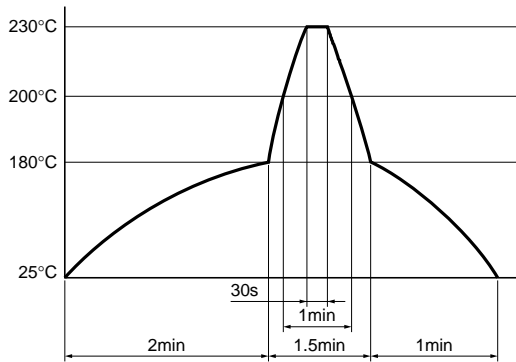


**Fig.14 Collector-emitter Saturation Voltage vs. Forward Current**



## Fig.15 Reflow Soldering

Only one time soldering is recommended within the temperature profile shown below.



### ■ Precautions for Use

Please refer to the chapter "Precautions for Use".